

Form PTO-1449  <b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b>  (Use several sheets if necessary)			ATTY DOCKET NO. 1768-000001/US		APPLICATION NO.	
			APPLICANT Tsuyoshi ONO, et al.		CONF. NO. Unknown	
			FILING DATE January 21, 2004		GROUP Unknown	

  

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE

  

FOREIGN PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
						YES	NO
HN	JP 11-134879	5/21/1999	JAPAN			ABST.	

  

OTHER DOCUMENTS (Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.		
HN		Giovanni Campardo, et al., "40-mm2 3-V-Only 50-MHz 64-Mb 2-v/Cell CHE NOR Flash Memory", IEEE Journal Of Solid-State Circuits, Vol. 35, No. 11, November 2000

  

EXAMINER <span style="font-size: 1.5em; font-family: cursive;">HIEN NGUYEN</span>	DATE CONSIDERED <span style="font-size: 1.5em; font-family: cursive;">4/1/05</span>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.